# **RF Exposure Evaluation Report**

Application No.:	DNT2503180445R2425-03060
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Applicant: Shenzhen Talos Technology Co., Ltd.

A801, Wuhan University Shenzhen Industry University Research Building,

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Address of Applicant: No. 6 Yuexing 2nd Road, High tech Zone Community, Yuehai Street,

Nanshan District, Shenzhen

**EUT Description:** TECHARRA Surge Guard

Model No.: TLS-SG-A1

FCC ID: 2BNPR-TLS-SG-A1

Power supply AC 110V/60HZ

Trade Mark: N/A

47 CFR Part 2.1091

Standards: FCC KDB 447498 D01 v06

**Date of Receipt:** 2025/03/19

**Date of Test:** 2025/03/20 to 2025/03/31

**Date of Issue:** 2025/04/05

Test Result: PASS

Prepared By: Wante Line (Testing Engineer)

Reviewed By: (Project Engineer)

Approved By: (Manager)



Note: If there is any objection to the results in this report, please submit a written inquiry to the company within 15 days from the date of receiving the report. The test report is effective only with both signature and specialized stamp, and is issued by the company in accordance with the requirements of the "Conditions of Issuance of Test Reports" printed in the attached page. Unless otherwise stated, the results presented in this report only apply to the samples tested this time. Partial reproduction of this report is not allowed unless approved by the company in writing.

Dongguan DN Testing Co., Ltd.



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### **Report Revise Record**

Report Version	Revise Time	Issued Date	Valid Version	Notes		
V2.0		Apr.5, 2025	Valid	Original Report		



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**General Information** 

### . Gonoral Informatio

# 1.1 Test Location

Company:	Dongguan DN Testing Co., Ltd
Address:	No. 1, West Fourth Street, South Xinfa Road, Wusha Liwu, Chang ' an Town, Dongguan City, Guangdong P.R.China
Test engineer:	Wayne Lin

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## 1.2 General Description of EUT

Manufacturer:	Shenzhen Talos Technology Co., Ltd.						
Address of Manufacturer:	A801, Wuhan University Shenzhen Industry University Research Building, No. 6 Yuexing 2nd Road, High tech Zone Community, Yuehai Street, Nanshan District, Shenzhen						
EUT Description:	TECHARRA Surge Guard						
Test Model No.:	TLS-SG-A1						
Additional Model(s):	1						
Chip Type:	PHY6252SD						
Serial number:	PR2503180445R2425						
Power Supply:	AC 110V/60Hz						
Trade Mark:	NA .						
Hardware Version:	V1.0						
Software Version:	V1.0						
Sample Type:	☐ Portable Device, ☐ Module,⊠ Mobile Device						
Antenna Type:	☐ External, ⊠ Integrated						
Antonno Coine	⊠ Provided by applicant						
Antenna Gain:	2.15dBi						

#### Remark:

<sup>\*</sup>Since the above data and/or information is provided by the applicant relevant results or conclusions of this report are only made for these data and/or information , DNT is not responsible for the authenticity, integrity and results of the data and information and/or the validity of the conclusion.



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## 1.3 Test Facility

The test facility is recognized, certified, or accredited by the following organizations:

#### Lab A:

#### • FCC, USA

Designation Number: CN1348

#### A2LA (Certificate No. 7050.01)

DONGGUAN DN TESTING CO., LTD. is accredited by the American Association for Laboratory Accreditation(A2LA). Certificate No. 7050.01.

#### • Innovation, Science and Economic Development Canada

DONGGUAN DN TESTING CO., LTD. EMC Laboratory has been recognized by ISED as an accredited testing laboratory. CAB identifier is CN0149.

IC#: 30755.

## 1.4 Measurement Uncertainty (95% confidence levels, k=2)

No.	Item	Measurement Uncertainty				
1	DTS Bandwidth	±0.0196%				
2	Maximum Conducted Output Power	±0.686 dB				
3	Maximum Power Spectral Density Level	±0.743 dB				
4	Band-edge Compliance	±1.328 dB				
5	Unwanted Emissions In Non-restricted Freq Bands	9KHz-1GHz:±0.746dB 1GHz-26GHz: ±1.328dB				

No.	Item	Measurement Uncertainty		
1	Conduction Emission	± 3.0dB (150kHz to 30MHz)		
	9, 9, 9, 9, 9,	± 4.8dB (Below 1GHz)		
	Dedicted Engineers	± 4.8dB (1GHz to 6GHz)		
2	Radiated Emission	± 4.5dB (6GHz to 18GHz)		
		± 5.02dB (Above 18GHz)		

## 2 RF Exposure Evaluation

## 2.1 RF Exposure Compliance Requirement

#### **2.1.1** Limits

Frequency range (MHz)	Electric field strength (V/m)	Magnetic field strength (A/m)	Power density (mW/cm2)	Averaging time (minutes)
	(A) Limits for Occup	oational/Controlled Expo	sures	
0.3-3.0	614	1.63	*(100)	6
3.0-30	1842/f	4.89/f	*(900/f2)	6
30-300	61.4	0.163	1.0	6
300-1500		1	f/300	6 6
1500-100,000			5	6
	(B) Limits for General P	opulation/Uncontrolled	Exposure	
0.3-1.34	614	1.63	*(100)	30
1.34-30	824/f	2.19/f	*(180/f2)	30
30-300	27.5	0.073	0.2	30
300-1500			f/1500	30
1500-100,000	1	1	1.0	30

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RF exposure compliance will need to be determined with respect to 1.1307(c) and (d) of the FCC rules. The emissions should be within the limits at 300kHz in Table 1 of 1.1310(use the 300kHz limits for 150kHz:614V/m,1.63A/m).

Friis Formula

Friis transmission formula: Pd = (Pout\*G)/(4\* Pi \* R 2)

Where

Pd = power density in mW/cm2

Pout = output power to antenna in mW

G = gain of antenna in linear scale

Pi = 3.1416

R = distance between observation point and center of the radiator in cm

Pd id the limit of MPE, 1 mW/cm2. If we know the maximum gain of the antenna and the total power input to the antenna, through the calculation, we will know the distance r where the MPE limit is reached.

F=frequency in MHz

<sup>\*=</sup>Plane-wave equivalent power density



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## 2.1.2 Test Procedure

Software provided by client enabled the EUT to transmit data at lowest, middle and highest channel individually

### 2.1.3 EUT RF Exposure Evaluation

Antenna Gain: The maximum Gain measured in fully anechoic chamber is 2.0 / 2.0 in linear scale.

Output Power Into Antenna & RF Exposure Evaluation Distance:

This confirmed that the device comply with MPE limit.

	Test Mode	Antenna	Freq(MHz)	Power [dBm]	
	,		2402	1.21	
	BLE 1M	Ant1	2440	0.45	
			2480	0.40	
		Ant1	2402	1.24	
	BLE 2M		2440	0.46	
			2480	0.50	

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					Anten	na gain		Limited		
The Worst Mode	Antenna	Peak output power (dBm)	Target power (dBm)	MAX Target power (dBm)	(dBi)	(Linear)	Power Density (S) (mW /cm²)	of Power Density (S) (mW /cm²)	Test Result	Distance (cm)
				2.40	3 Band				X	
BLE 2M	Ant1	1.24	1±1	2	2.15	1.641	0.0005	1	Complies	20

The End Report